

Ultra-Broadband Silicon Capacitor UBSC 0402 100nF BV11



Rev. 3.00

General description

UBSC Capacitor targets Optical communication system such as ROSA/TOSA, SONET and all optoelectronics as well as High speed data system or products.

The UBSC is suitable for DC blocking, feedback, coupling and bypassing applications in all broadband optoelectronics and High-speed data system.

The unique technology of integrated passive device in silicon, developed by Murata Integrated Passive Solutions, offers unique performances with low insertion loss, low reflection and phase stability from 16 KHz to 60 GHz+.

These capacitors in ultra-deep trenches in silicon have been developed in a semiconductor process, in order to integrate trench MOS capacitor providing high capacitance value of 100nF (for kHz–MHz range) and high frequency MIM capacitors for low capacitance value for GHz range), combined in a 0402 [1.2x0.7mm] case.

The UBSC capacitor provides very high stability of the capacitance over temperature, voltage variation as well as a very high reliability.

UBSC capacitors have an extended operating temperature ranging from -55 to 150°C, with very low capacitance change over temperature (+70ppm/K).

Assembly: Suitable for surface mounted application on rigid PCB, ceramic substrate, FR4 (laminate) or flex platforms.

Bump finishing: ENIG

Copper pads optional for embedding version and SAC305 type 6 for pre-bumping version, as an optional finishing.

Key features

- Ultra-Large band performance up to 67 GHz
- Resonance free
- Phase stability
- Insertion low < 0.3dB Typ. up to 60 GHz
- Ultra-high stability of capacitance value:
 - Temperature 70ppm/K (-55 °C to +150 °C)
 - Voltage < -0.1%/Volt
 - Negligible capacitance loss through ageing
- Low profile: 400µm, 100 µm on request
- Break down voltage : 11V
- Low leakage current < 100pA
- High reliability
- High operating temperature (up to 150 °C)
- Compatible with high temperature cycling during manufacturing operations (exceeding 300 °C)
- Compatible with EIA 0402 footprint

Key applications

- ROSA/TOSA
- SONET
- High speed digital logic
- Microwave/millimetre system
- High volumetric efficiency (i.e. capacitance per unit volume)
- Broadband test equipment

Functional diagram

The next figure provides implementation set-up diagram.



Figure 1 Block Diagram

Electrical performances

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
C	Capacitance value	@+25°C	-	100	-	nF
ΔC_P	Capacitance tolerance ⁽¹⁾	@+25°C	-15	-	+15	%
T _{OP}	Operating temperature		-55	20	150	°C
T _{STG}	Storage temperature ⁽²⁾		-70	-	165	°C
ΔC_T	Capacitance temperature variation	-55 °C to 150 °C	-	70	-	ppm/K
RV _{DC}	Rated voltage ⁽³⁾		-	-	3.8 ⁽⁴⁾ 3.4 ⁽⁵⁾	V _{DC}
BV	Break down voltage	@+25°C	11	-	-	V
ΔC_{RVDC}	Capacitance voltage variation	From 0 V to RV _{DC} , @+25°C	-	-	-0.1	%/V _{DC}
IR	Insulation resistor	@RV _{DC} , +25°C, 120s	-	10	-	GΩ
ESL	Equivalent Serial Inductance	@+25°C, SRF shunt mode	-	180	-	pH
ESR	Equivalent Serial Resistance	@+25°C, shunt mode	-	400	-	mOhm
Fc-3dB	Cut-off frequency at 3dB	@+25°C	-	16	19	kHz
IL	Insertion loss	@ 20 GHz, +25°C	-	0.2	-	dB
		@ 40 GHz, +25°C	-	0.4	-	dB
		@ 60 GHz, +25°C	-	0.8	-	dB
RL	Return loss	Up to 60 GHz, +25°C	14	-	-	dB
ESD	HBM stress ⁽⁶⁾	JS-001-2017	2	-	-	kV

Table 1 - Electrical performances

⁽¹⁾: other tolerance available upon request.

⁽²⁾: without packaging.

⁽³⁾: Lifetime is voltage and temperature dependent, please refer to application note 'Lifetime of 3D capacitors'.

⁽⁴⁾: 10 years of intrinsic life time prediction at 100°C continuous operation.

⁽⁵⁾: 10 years of intrinsic life time prediction at 150°C continuous operation.

⁽⁶⁾: please refer to application note 'ESD Challenge in 3D Murata Integrated Passive technology'.

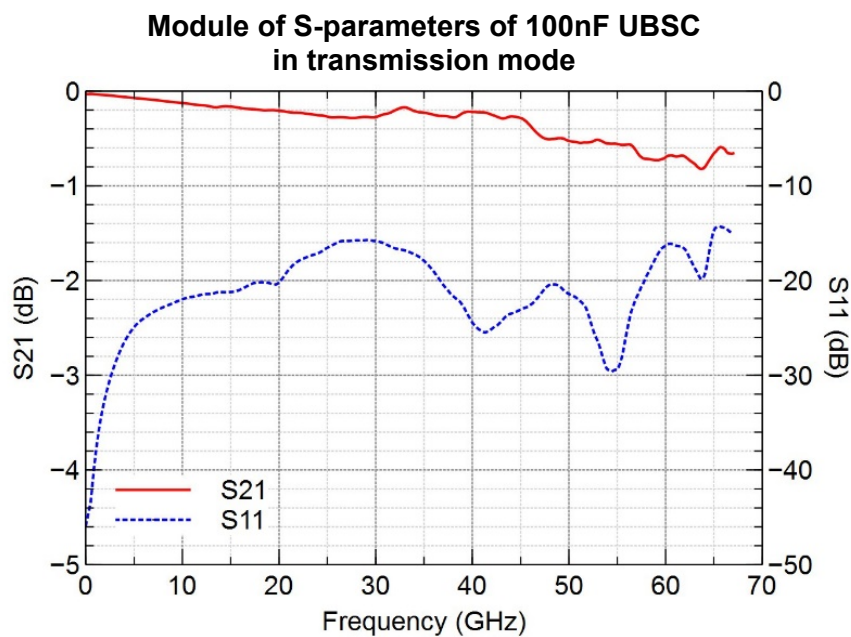
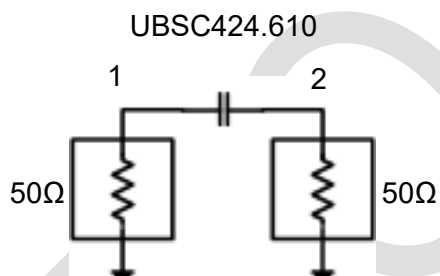


Figure 2 - 100nF UBSC Measured results
(module of S-parameters)

Schematic of 100nF UBSC in transmission mode



10-mil Rogers 4350B.

Microstrip mode – line width = 0.551mm and gap = 0.246 mm.
(nominal 50 ohm characteristic impedance).

Figure 3 - 100nF UBSC measurement schematic

Example of 0402 surface mounted

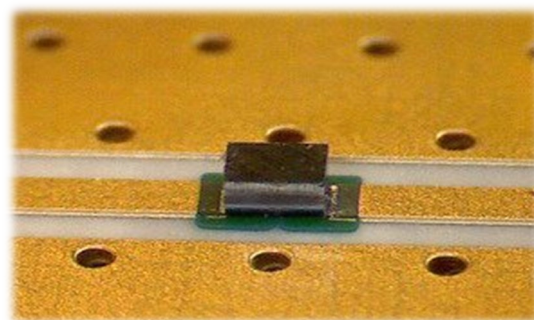


Figure 4 – micro picture of UBSC mounted on board
in coplanar mode



Pinning definition

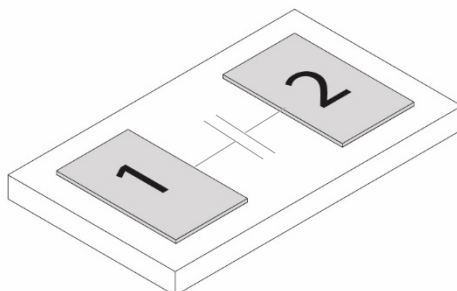


Figure 5 Pinning definition

pin #	Symbol	Coordinates X / Y
1	Signal	-350.0 / 0.0
2	Signal	350.0 / 0.0

Table 2 - Pinning description. Reference (0,0) located at the centre of the die.

Ordering Information

Murata Integrated Passive Devices delivers products with AQL level II (0.65). Tighter quality levels are available upon request.

Part number	Package		
	Packaging	Finishing	Description
935151424610-F1N	6" film frame carrier ⁽¹⁾	ENIG ⁽²⁾	UBSC 0402 - 100nF – 2 pads – 1.2 x 0.7mm x 0.40mm ⁽⁴⁾
935151424610-T3N	T&R 1 000units ⁽³⁾	ENIG ⁽²⁾	UBSC 0402 - 100nF – 2 pads – 1.2 x 0.7mm x 0.40mm ⁽⁴⁾
935152424610-F1N	6" film frame carrier ⁽¹⁾	ENIG ⁽²⁾	UBSC 0402 - 100nF – 2 pads – 1.2 x 0.7mm x 0.10mm ⁽⁴⁾
935152424610-T3N	T&R 1 000units ⁽³⁾	ENIG ⁽²⁾	UBSC 0402 – 100nF – 2 pads – 1.2 x 0.7mm x 0.1mm ⁽⁴⁾

Table 3 - Packaging and ordering information

- (1) Other film frame carriers are possible on request
 (2) ENIG : 0.1µm Au / 5µm Ni
 (3) missing capacitors can reach 0.5%
 (4) refer to figure 7

Product Name	Die Name	Description
UBSC424.610	XC0402610	UBSC 100nF / 0402 / BV11 – 2 pads – 1.2 x 0.7 x 0.40mm
UBSC424.610	XC0402610	UBSC 100nF / 0402 / BV11 – 2 pads – 1.2 x 0.7 x 0.10mm

Table 4 - Die information

Pad Metallization

This surface mounted Silicon Capacitor is delivered as standard with NiAu (ENIG (0.1 μ m Au / 5 μ m Ni)).

Other Metallization, such as Copper, Thick Gold or Aluminum pads are possible on request.

Silicon dies are not sensitive to humidity, please refer to applications notes 'Assembly Notes' section 'Handling precautions and storage'.

Material regulation

This product is RoHS compliant at the time of publication. For further information about regulation compliancy, please ask your sales representative.

Package outline

The product is delivered as a bare silicon die.

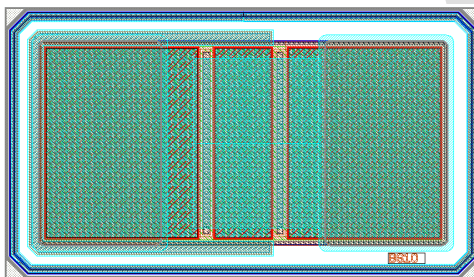


Figure 6 – Layout view

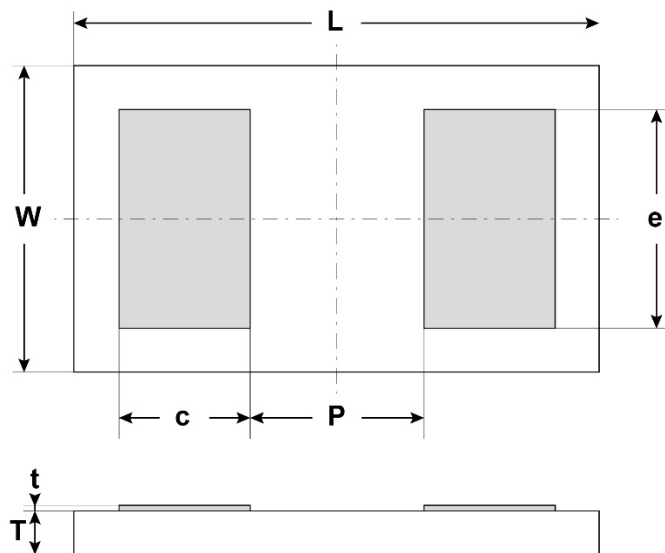


Figure 7 - Package isometric view

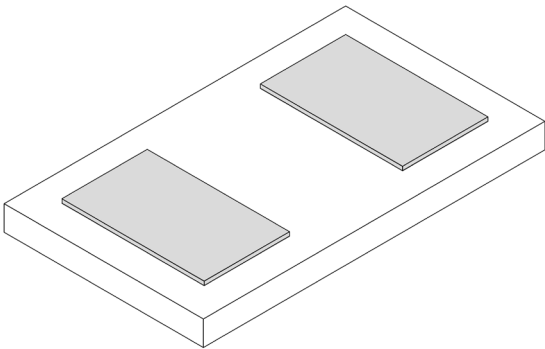


Figure 8 - Package isometric view

L (mm)	W (mm)	T (mm)	c (mm)	p (mm)	e (mm)	t (mm)
1.20 ± 0.04	0.70 ± 0.04	0.40 or 0.10 ± 0.01	0.30	0.40	0.50	0.005 ⁽¹⁾

Table 5 - Dimensions and tolerances

(1) Standard with ENIG

Assembly

The attachment techniques recommended by Murata on the customer’s substrates are fully detailed in specific documents available on our website. To assure the correct use and proper functioning of Murata capacitors **please download the assembly instructions on <https://www.murata.com/en-us/products/capacitor/siliconcapacitors> and read them carefully.**



Figure 9 Scan this QR Code to access the Murata Silicon Capacitor web page

Packaging format

Please refer to application note 'Products Storage Conditions and Shelf Life'.

Tape and Reel:

Dies are flipped in the tape cavity (bump down) with die ID located near the driving holes of the tape.

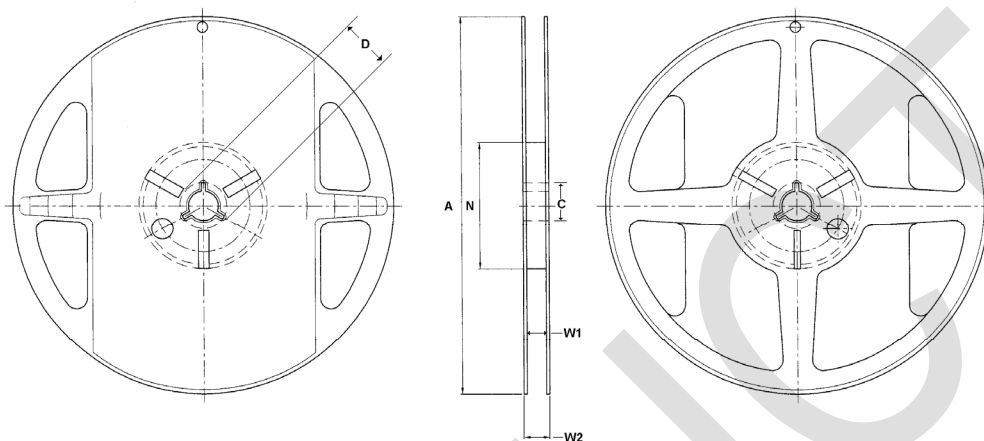


Figure 10 - Reel drawing

Tape Width	Diameter A	C	D	Hub N	W1	W2
8	178 (7 inches)	13.5	20.2	60	9.3	11.5

Table 6 – Reel dimensions (mm)

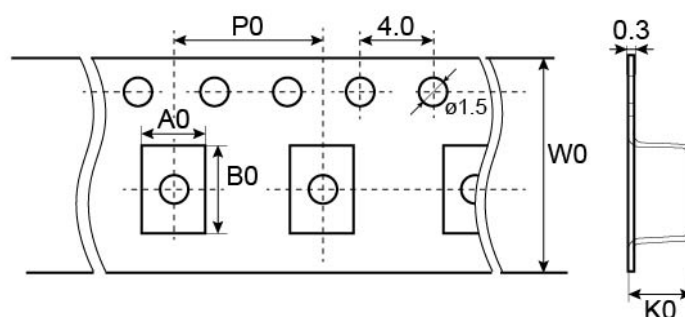


Figure 11 - Tape drawing

Cavity dimensions			Carrier tape width W0	Carrier tape pitch P0	Reel Capacity
Ao	Bo	Ko			
0.92	1.31	0.56	8	4	1 000

Table 7 - Tape dimensions (mm)



Film Frame Carrier:

With UV curable dicing tape (UV performed).

Good dies are identified using the SINF electronic mapping format. No ink is added on wafer to label other dies.

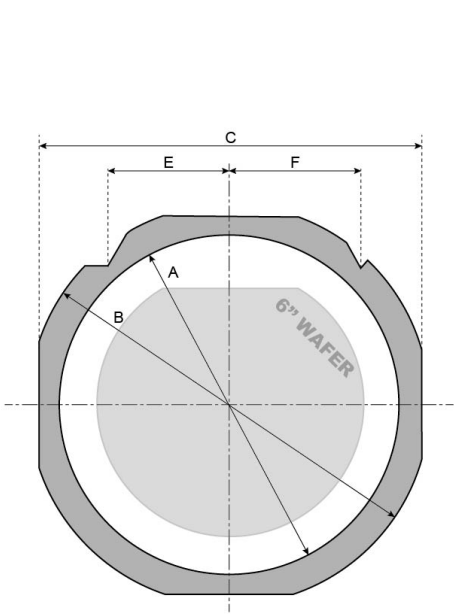


Figure 12 FF070 Frame with a 6 inch wafer

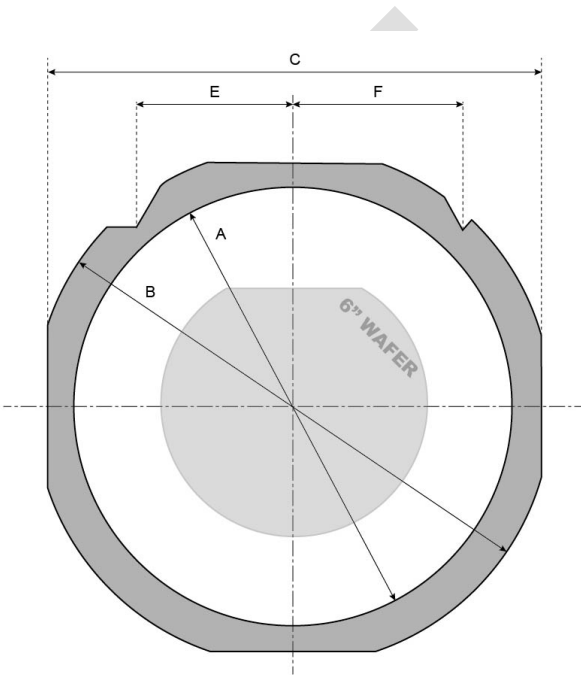


Figure 13 FF108 Frame with a 6 inch wafer

Frame Reference	Frame Style	Inside diameter A	Outside diameter B	Width C	Thickness	Pin location E	Pin location F
FF070 (1)	DTF-2-6-1	7.638"	8.976"	8.346"	0.048"	2.370"	2.5"
FF108 (1)	DTF-2-8-1	9.842"	11.653"	10.866"	0.048"	2.381"	2.5"

Table 8 - Frame dimensions (inches)

(1) or equivalent



Expander grip ring 6" diameter:

With UV curable dicing tape (UV performed)

Good dies are identified using the SINF electronic mapping format. No ink is added on wafer to label other dies.

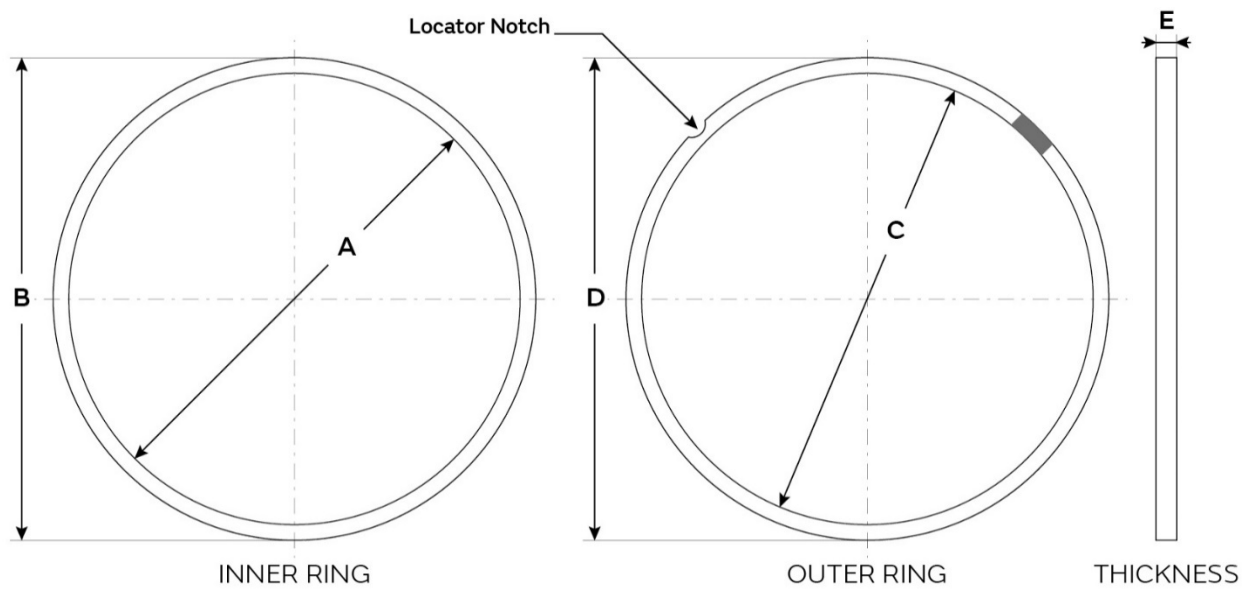


Figure 14 – Grip Ring drawing

Grip Ring Style	A	B	C	D	E	Locator Notch
GRP-2620-6 ⁽¹⁾	7.670"	7.973"	7.975"	8.280"	0.236"	None

Table 9 - Frame dimensions (inches)

(1) or equivalent

PRO

Definitions

Data sheet status

Objective specification: This data sheet contains target or goal specifications for product development.

Preliminary specification: This data sheet contains preliminary data; supplementary data may be published later.

Product specification: This data sheet contains final product specifications.

Limiting values

Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those given in the Electrical performances sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

Revision history

Revision	Date	Description	Author
Release 1.00	2014 February 18 th	Objective specification	LDU
Release 2.02	2020 June 17 th	Template Change – content changes	OGA
Release 3.00	2021 May 06 th	Product revision	CGU, LLR, DDE, SCA, DYO, OGA

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